Bulletin PD-21054 rev. B 08/06

International
IOR Rectifier

30WQ06FNPbF

SCHOTTKY RECTIFIER

3.5 Amp

$I_{F(AV)}$ = 3.5Amp
V_R = 60V

Major Ratings and Characteristics

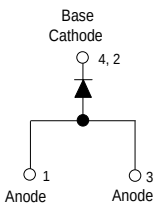
Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	3.5	A
V_{RRM}	60	V
I_{FSM} @tp = 5 µs sine	490	A
V_F @3 Apk, T_J = 125°C	0.53	V
T_J	-40 to 150	°C

Description/ Features

The 30WQ06FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

Case Styles



D-PAK (TO-252AA)

Voltage Ratings

Part number		30WQ06FNPbF
V_R	Max. DC Reverse Voltage (V)	60
V_{RWM}	Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters		30WQ...	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current * See Fig. 5	3.5	A	50% duty cycle @ T_C = 133°C, rectangular wave form	
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	490	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
		70		10ms Sine or 6ms Rect. pulse	
E_{AS}	Non-Repetitive Avalanche Energy	6.0	mJ	T_J = 25 °C, I_{AS} = 1 Amp, L = 12 mH	
I_{AR}	Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A = 1.5 x V_R typical	

Electrical Specifications

Parameters		30WQ...	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop * See Fig. 1 (1)	0.61	V	@ 3A	T_J = 25 °C
		0.76	V	@ 6A	
		0.53	V	@ 3A	T_J = 125 °C
		0.65	V	@ 6A	
I_{RM}	Max. Reverse Leakage Current * See Fig. 2 (1)	2	mA	T_J = 25 °C	V_R = rated V_R
		30	mA	T_J = 125 °C	
$V_{F(TO)}$	Threshold Voltage	0.38	V	T_J = T_J max.	
r_t	Forward Slope Resistance	34.31	mΩ		
C_T	Typical Junction Capacitance	145	pF	V_R = 5V_{DC} (test signal range 100Khz to 1Mhz) 25 °C	
L_S	Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V_R)	

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters		30WQ...	Units	Conditions
T_J	Max. Junction Temper. Range (*)	-40 to 150	°C	
T_{stg}	Max. Storage Temperature Range	-40 to 150	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case	4.7	°C/W	DC operation * See Fig. 4
wt	Approximate Weight	0.3 (0.01)	g (oz.)	
	Case Style	D - PAK		Similar to TO-252AA
	Marking Device	30WQ06FN		

(*) $\frac{dPtot}{dTj} < \frac{1}{Rth(j\text{-}a)}$ thermal runaway condition for a diode on its own heatsink

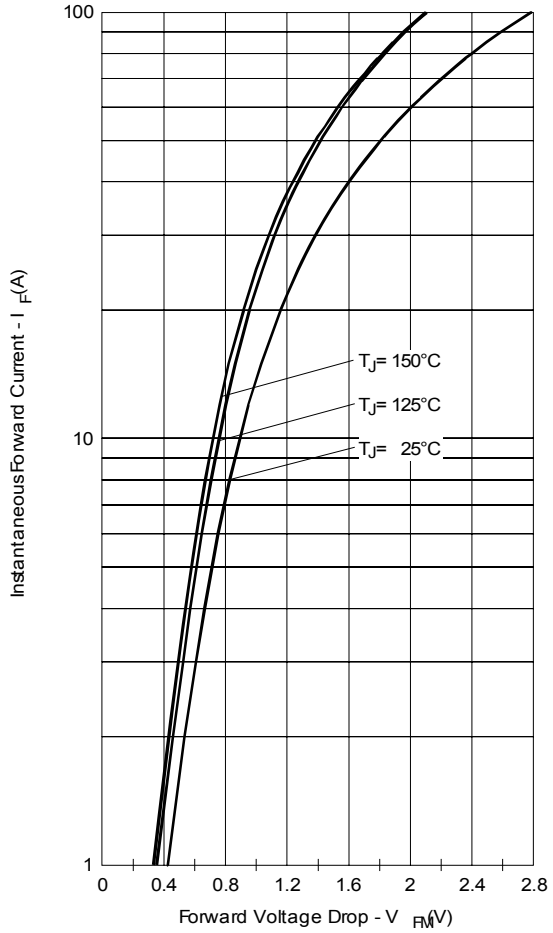


Fig. 1 - Maximum Forward Voltage Drop Characteristics

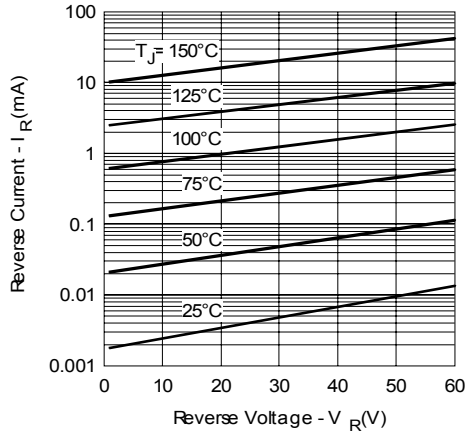


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

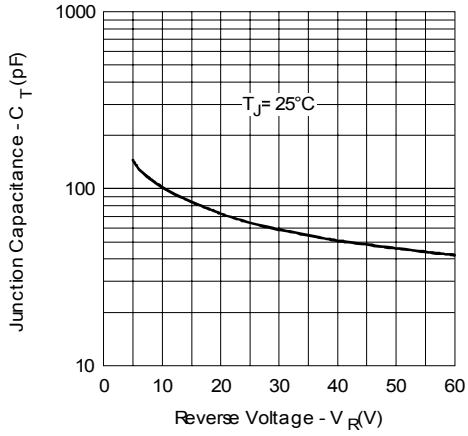


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

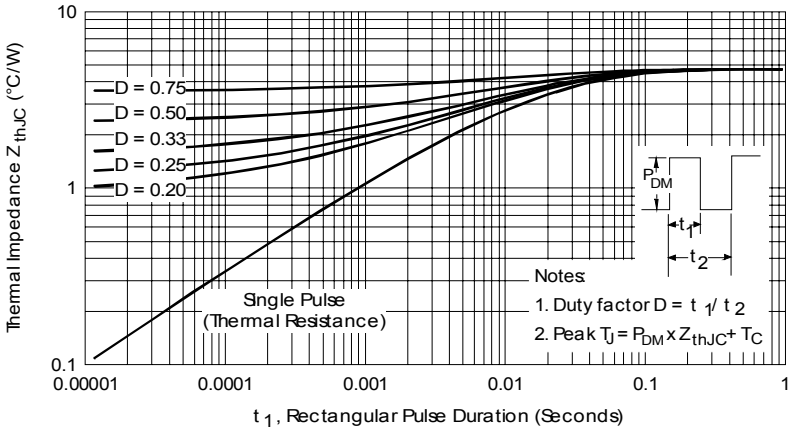


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

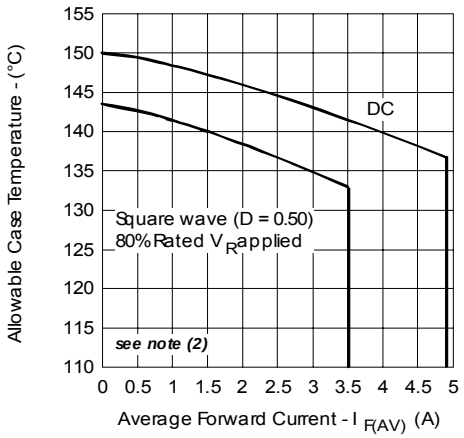


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

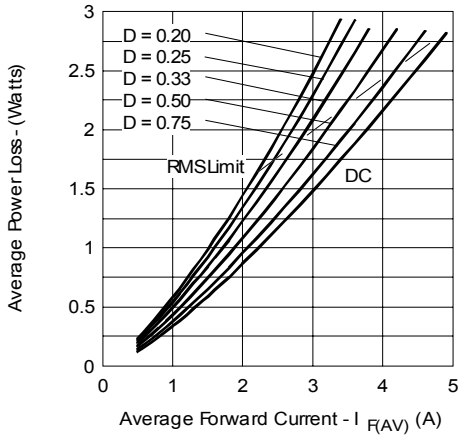


Fig. 6 - Forward Power Loss Characteristics

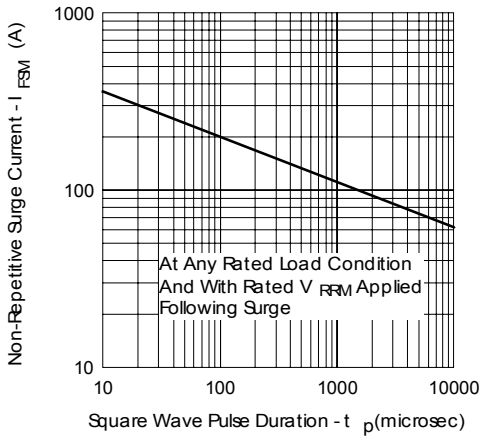
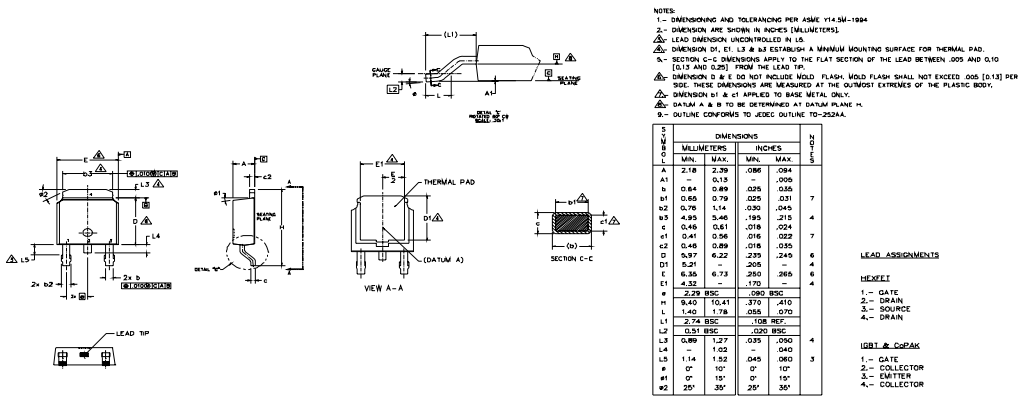


Fig. 7 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = 80% rated V_R

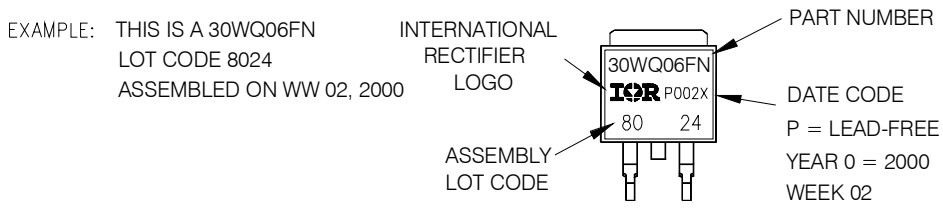
Outline Table



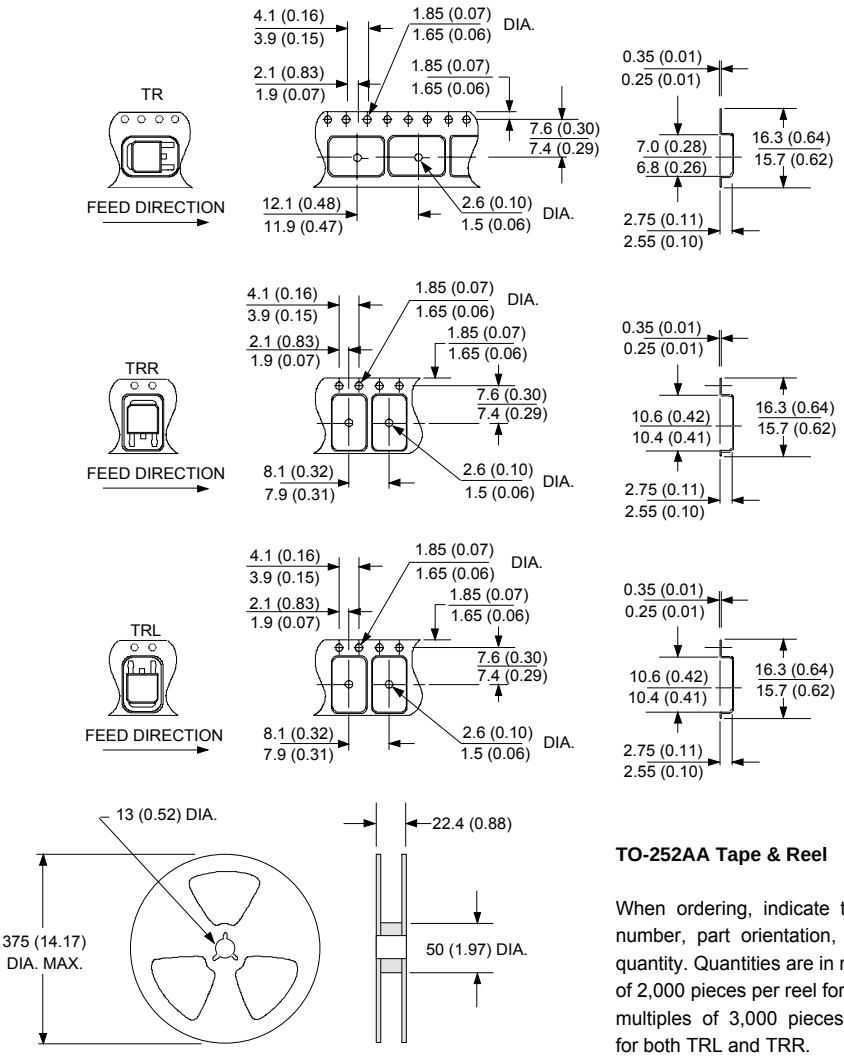
SYMBOL	DIMENSIONS				NOTES
	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	2.18	2.39	.086	.094	
A1	–	0.13	–	.005	
b	0.64	0.89	.025	.035	
b1	0.65	0.79	.025	.031	7
b2	0.78	1.14	.030	.045	
b3	4.95	5.46	.195	.215	4
c	0.46	0.61	.018	.024	
c1	0.41	0.56	.016	.022	7
c2	0.46	0.89	.018	.035	
D	5.97	6.22	.235	.245	6
D1	5.21	–	.205	–	4
E	6.35	6.73	.250	.265	6
E1	4.32	–	.170	–	4
e	2.29 BSC		.090 BSC		
H	9.40	10.41	.370	.410	
L	1.40	1.78	.055	.070	
L1	2.74 BSC		.108 REF.		
L2	0.51 BSC		.020 BSC		
L3	0.89	1.27	.035	.050	4
L4	–	1.02	–	.040	
L5	1.14	1.52	.045	.060	3
ø	0°	10°	0°	10°	
ø1	0°	15°	0°	15°	
ø2	25°	35°	25°	35°	

Modified JEDEC outline TO-252AA
Dimensions in millimeters and (inches)

Part Marking Information



Tape & Reel Information

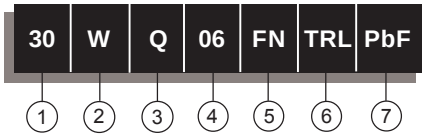


TO-252AA Tape & Reel

When ordering, indicate the part number, part orientation, and the quantity. Quantities are in multiples of 2,000 pieces per reel for TR and multiples of 3,000 pieces per reel for both TRL and TRR.

Ordering Information Table

Device Code



1	-	Current Rating (3.5A)
2	-	Package Identifier W = D-Pak
3	-	Schottky "Q" Series
4	-	Voltage Rating (06 = 60V)
5	-	FN = TO-252AA (D-Pak)
6	-	• none = Tube (50 pieces) • TR = Tape & Reel • TRL = Tape & Reel (Left Oriented) • TRR = Tape & Reel (Right Oriented)
7	-	• none = Standard Production • PbF = Lead-Free

Data and specifications subject to change without notice.
This product has been designed and qualified for AEC Q101 Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 08/06